

THE SPECIFICATION OF AlGaAs IR LED CHIP "PR7A96"

1. DESCRIPTION

This is a AlGaAs red LED chip. It is N-side up.

2. ELECTRO - OPTICAL CHARACTERISTICS (Ta=25deg. C)

CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage (Vf) IF=20mA		1.8		V
Reverse Voltage (Vr) IR=10uA	5			V
Radiated Power ¹⁾ (Po) IF=20mA	1.2			mW
Peak Wavelength (λp) IF=20mA	645	670	675	nm

1) LED chip is mounted on TO-18 gold header without resin coated.

3. ABSOLUTE MAXIMUM RATINGS

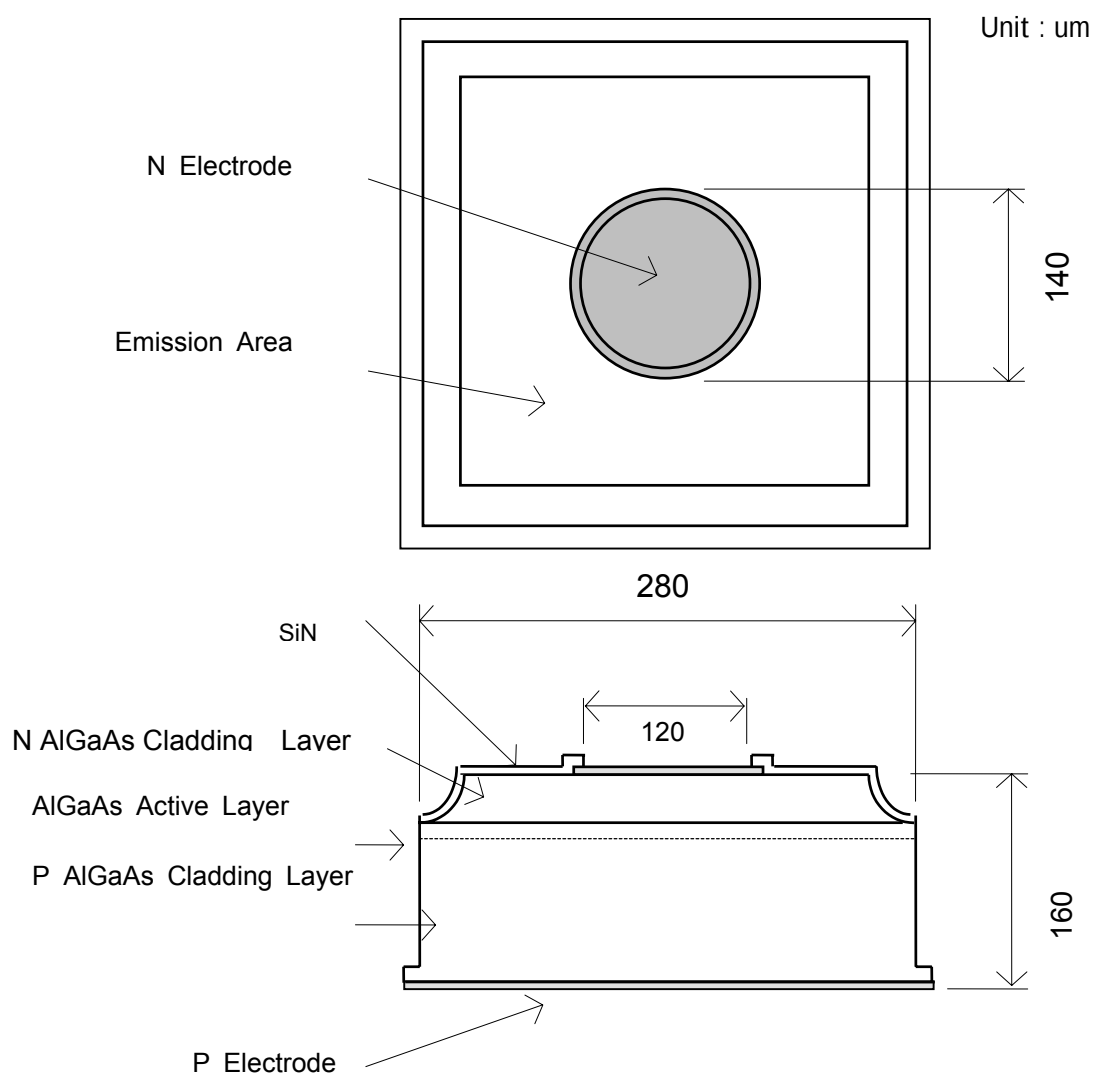
Continuous Maximum Forward Current	: 50 mA(DC)
Reverse Voltage	: 5 V(IR=10uA)
Storage Temperature	
while on mylar membrane	: 0 to 40 deg. C
after removal from mylar membrane	: -30 to 100 deg. C

4. PHYSICAL CHARACTERISTICS AND STRUCTURE

- 1)Material : AlGaAs
- 2)Structure : Double Hetero Structure
- 3)Die size : 0.310mmX0.310mm
- 4)Junction Size : 0.280mmX0.280mm
- 5)Thickness : 0.160mm
- 6)Bond Pad Size : 0.140mm diameter
- 7)Anode Metallization : Gold Alloy
- 8)Cathode Metallization : Gold Alloy

Physical Dimensions

Model PR7A96 *



Remark: This specification is for reference purpose only, and subject to change without prior notice.
Approved specification shall be obtained for the regular purchase.